



SLPS216A - FEBRUARY 2010-REVISED JULY 2010

30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17302Q5A

FEATURES

- **Optimized for 5V Gate Drive**
- Ultralow Q_g and Q_{gd}
- **Low Thermal Resistance**
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

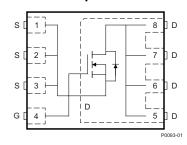
APPLICATIONS

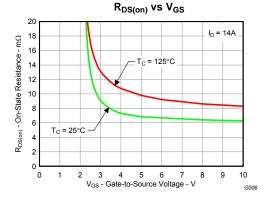
- **Notebook Point of Load**
- Point-of-Load Synchronous Buck in **Networking, Telecom and Computing Systems**

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.

Top View





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 30			
Q_g	Gate Charge Total (4.5V)	5.4		nC
Q_{gd}	Gate Charge Gate to Drain	1.2	nC	
		$V_{GS} = 3V$	9.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V$ 7.3		mΩ
		V _{GS} = 8V 6.4		mΩ
$V_{GS(th)}$	Threshold Voltage	1.2		٧

ORDERING INFORMATION

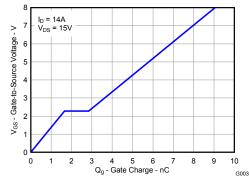
Device	Package	Media	Qty	Ship
CSD17302Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	٧
V_{GS}	Gate to Source Voltage	+10 / -8	٧
	Continuous Drain Current, T _C = 25°C	87	Α
I _D	Continuous Drain Current ⁽¹⁾	16	Α
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	104	Α
P_D	Power Dissipation ⁽¹⁾	3	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse I_D = 35A, L = 0.1mH, R_G = 25 Ω	61	mJ

- (1) Typical $R_{\theta JA} = 41^{\circ}\text{C/W}$ on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Ch	naracteristics		·			
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30			V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V$, $V_{DS} = 24V$			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10 / -8V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.9	1.2	1.7	V
		V _{GS} = 3V, I _D = 14A		9.5	128	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 14A		7.3	9	mΩ
		V _{GS} = 8V, I _D = 14A		6.4	7.9	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _D = 14A		68		S
Dynamic	Characteristics	•	•		•	
C _{iss}	Input Capacitance			730	950	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$		390	510	pF
C _{rss}	Reverse Transfer Capacitance			35	45	pF
R _G	Series Gate Resistance			0.8	1.6	Ω
Qg	Gate Charge Total (4.5V)			5.4	7	nC
Q _{gd}	Gate Charge Gate to Drain	V _{DS} = 15V, I _D = 14A		1.2		nC
Q _{gs}	Gate Charge Gate to Source			1.7		nC
Q _{g(th)}	Gate Charge at Vth			0.9		nC
Q _{oss}	Output Charge	V _{DS} = 13V, V _{GS} = 0V		9.5		nC
t _{d(on)}	Turn On Delay Time			5.2		ns
t _r	Rise Time	V _{DS} = 15V, V _{GS} = 4.5V,		8.4		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 14A, R_G = 2\Omega$		10.6		ns
t _f	Fall Time			3.1		ns
Diode Ch	naracteristics				,	
V_{SD}	Diode Forward Voltage	I _{SD} = 14A, V _{GS} = 0V		0.85	1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = 13V, I _F = 14A,		15.4		nC
t _{rr}	Reverse Recovery Time	di/dt = 300A/μs		17.5		ns

THERMAL CHARACTERISTICS

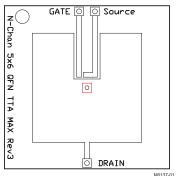
(T_A = 25°C unless otherwise stated)

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			1.8	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (1)(2)			51	°C/W

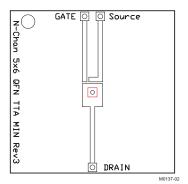
 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

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Max $R_{\theta JA} = 51^{\circ} C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 125^{\circ} C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

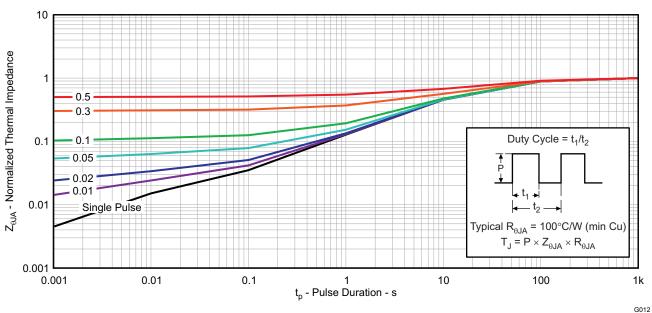


Figure 1. Transient Thermal Impedance

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

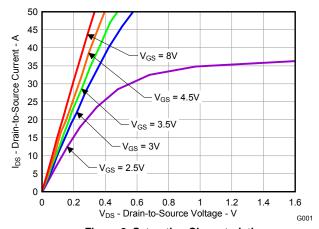


Figure 2. Saturation Characteristics

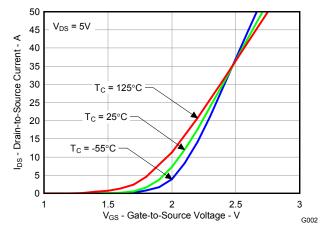


Figure 3. Transfer Characteristics

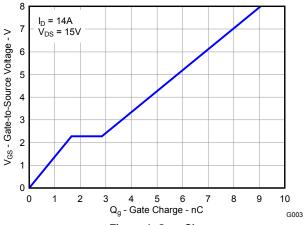


Figure 4. Gate Charge

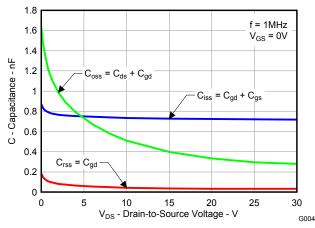


Figure 5. Capacitance

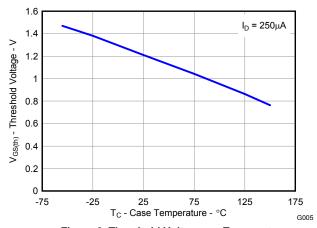


Figure 6. Threshold Voltage vs. Temperature

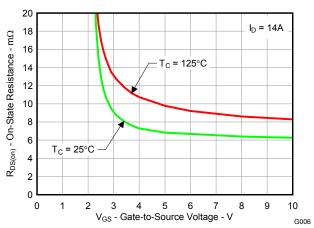


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

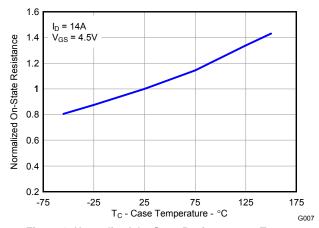


Figure 8. Normalized On-State Resistance vs. Temperature

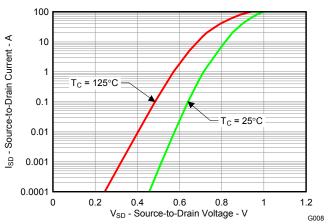


Figure 9. Typical Diode Forward Voltage

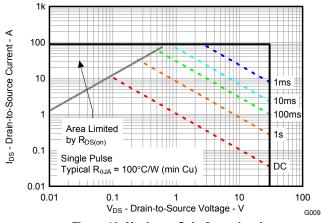


Figure 10. Maximum Safe Operating Area

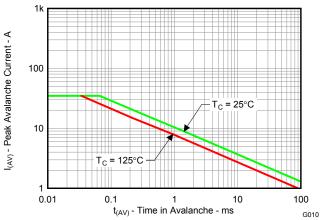


Figure 11. Single Pulse Unclamped Inductive Switching

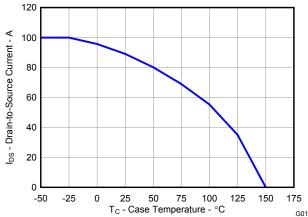
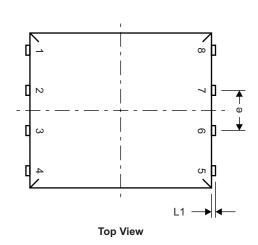


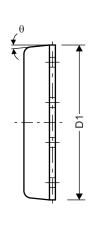
Figure 12. Maximum Drain Current vs. Temperature



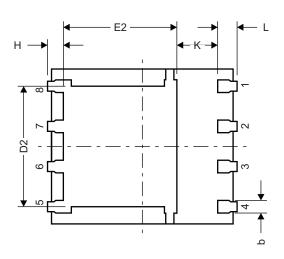
MECHANICAL DATA

Q5A Package Dimensions





Side View



Bottom View

Front View

M0135-01

DIM		MILLIMETERS	
DIM	MIN	NOM	MAX
Α	0.90	1.00	1.10
b	0.33	0.41	0.51
С	0.20	0.25	0.34
D1	4.80	4.90	5.00
D2	3.61	3.81	4.02
Е	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
е	1.17	1.27	1.37
Н	0.41	0.56	0.71
K	1.10		
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
θ	0°		12°

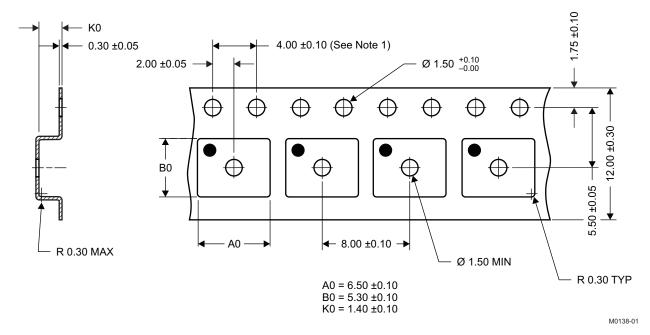


Recommended PCB	Pattern
F6 - F1	F7
F10 F10	M0139-01 4 7 4 8 7 7 8 7 8 7 8 7 8 8 8 8

DIM	MILLIN	IETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

SLPS216A - FEBRUARY 2010-REVISED JULY 2010



REVISION HISTORY

CI	hanges from Original (February 2010) to Revision A	Page
•	Updated the Q5A Package Dimensions table. DIM c MAX was 0.30, DIM D2 MAX was 3.96, DIM e MIN was blank MAX was blank, DIM H NOM was 0.51 MAX was 0.61	6
•	Deleted Note 6 from the Q5A Tape and Reel Information - "MSL1 260°C (IR and convection) PbF reflow compatible"	7
•	Deleted the Package Marking Information section	7

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CSD17302Q5A	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17302
CSD17302Q5A.B	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17302

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

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